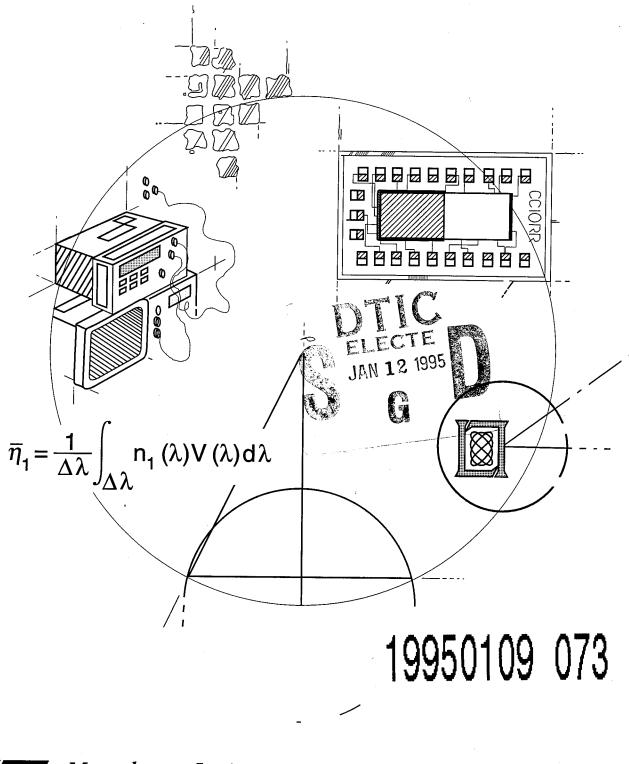
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FOR THE COMMANDER

11 Gary Tutungian

Administrative Contracting Officer Contracted Support Management

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INTRODUCTION

S ince its establishment in 1951, MIT Lincoln Laboratory has actively pursued its mission to "carry out a program of research and development pertinent to national defense with particular emphasis on advanced electronics." Toward this end, the Laboratory promotes scientific and technological research providing the best solutions to address the needs of the nation. By patenting and licensing inventions, technology originally developed to meet the specific needs of the Department of Defense and other government agencies can be applied to solve problems in the civilian sector; this substantially benefits the nation's economy and serves as an impetus for improving society worldwide.

EXECUTIVE SUMMARY

 \mathbf{M} assachusetts Institute of Technology maintains close ties with industry to enhance both the vitality and relevance of its education and research. This steady flow of ideas between the Institute and the commercial world has established the Institute and Lincoln Laboratory as global leaders in technological competitiveness. For instance, the Laboratory has had a major role in developing diode laser technology for numerous military and civilian applications. Particularly significant has been the development of 1.3-1.5 μ m diode lasers, which are now widely used as sources in fiber communications. The Laboratory has contributed significant advances in the areas of radar, physics, electronics, aerospace technology, new materials, communications, optics, lasers, solid state physics, artificial intelligence, neural networks, photovoltaics, superconductivity, semiconductors, health care, and computer hardware and software development; noteworthy contributions have also been made in the fields of air traffic control, environmental science, and solar energy.

Lincoln Laboratory's professional staff of approximately 1,200 members exemplifies the creativity, imagination, and innovation that has generated about seven invention disclosures each month. Eighty-five percent of the professional staff hold advanced degrees, two-thirds of which are in electrical engineering and physics disciplines, with others in diversified scientific fields and subject areas. Their breadth of education, skills, and experience meet the demands of sponsors' changing needs and the challenge to further an integrated approach in solving complex problems.

Since 1951, Lincoln Laboratory has effectively transferred its technology to industry, patenting 243 inventions, 69 of which are licensed, together generating over \$21 million. Many of these inventions have been protected worldwide. Moreover, some inventions, like the Solid State Laser of Dr. Aram Mooradian and the Diffractive/Refractive Lens Implant of Dr. Gary J. Swanson (see Selected Profiles in Creativity), can be considered breakthroughs that will bring about the creation of new industries, ensuring Lincoln Laboratory leadership in the scientific and technical communities.

In addition, a large number of "spin-off" companies have been started with Lincoln-developed technology. An example is Digital Equipment Corporation (DEC), founded in 1957 by Kenneth H. Olsen using technology developed at the Laboratory; DEC recently reported an annual sales figure of \$12.741 billion and a work force of 124,500 employees worldwide. Another example is Lasertron, begun in 1980, which has a reported \$22 million in sales with 230 employees. These are examples of companies that have made effective use of the potential of the Laboratory's research. In fact, Lincoln has an impressive number of spin-off companies: over the years, 63 have been spawned, employing more than 135,000 people and generating more than \$14.1 billion in sales annually.¹

Besides patents, Lincoln Laboratory promotes and furthers the intellectual and economic robustness of the country in several significant ways. Over the years, Laboratory reseachers have authored over 60 books and each year they produce more than 500 journal articles, technical presentations at national and international conferences, and technical reports on a variety of topics in many fields.² In 1988, the *Livcolin Laboratory Journal* was launched; this publication is distributed to almost 6,000 persons, agencies, institutions, and companies throughout the country.

¹ Spin-Off Companies from MIT Lincoln Laboratory, Lexington, Mass.: MIT Lincoln Laboratory (June 1990).

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² Unclassified Publications of Lincoln Laboratory, Lexington, Mass.: MIT Lincoln Laboratory (annual).

Finally, the Laboratory exchanges technical information with all branches of the Department of Defense, other government agencies, academia, and industry. This interchange is encouraged by the numerous professional visits made to the Laboratory: each year, over 20,000 visitors are drawn to our technical seminars, workshops, briefings, and demonstrations.

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THE TECHNOLOGY LICENSING OFFICE (TLO)

T he Technology Licensing Office works with industry, venture capital sources, and entrepreneurs to find the best way to commercialize the new technologies developed at MIT and Lincoln Laboratory. Historically, the Massachusetts Institute of Technology's approach has been to patent inventions. Four years ago, however, the Institute brought a greater emphasis to licensing. The success of this change is impressive with over 100 patents issued last year alone; 48% of these patents licensed or optioned at the time of issue. A branch office opened at Lincoln Laboratory just two years ago was a direct outcome of this success.

SELECTED PROFILES IN CREATIVITY



JAY W. FORRESTER HOLDS AN ARRAY CONTAINING OVER 1000 TINY MAGNETIC CORES DEVELOPED AT MIT TO SERVE AS THE "MEMORY" FOR THE INSTITUTE'S WHIRLWIND I COMPUTER.

JAY FORRESTER received a B.S. in Electrical Engineering from the University of Nebraska and an S.M. in Electrical Engineering from the Massachusetts Institute of Technology. From 1952 until 1956, he was Head of Lincoln Laboratory's Digital Computer Division. In 1956, he joined the MIT faculty as professor at its Sloan School of Management. Since 1972, he has been the Germeshausen Professor of Management at Sloan where he directs the Systems Dynamics Program.

Invention: Multicoordinate Digital Information Storage (Magnetic Core Memory) Device

The magnetic core memory device, patented in 1956, consisted of a plane array of small doughnutshaped ferrite cores; four wires threaded through each core carry current pulses that were used to sense the information stored in the memory and to write in new information. This concept increased both the speed and reliability of computer memory systems. For over two decades, random-access, coincident-current magnetic storage was the standard memory device for high-speed digital computers. Jay Forrester holds the basic patent for this invention.

United States patent 2,736,880 has been granted for this invention.



DR. ALICE M. CHIANG WITH HER CHARGE-DOMAIN PARALLEL PROCESSING NETWORK.

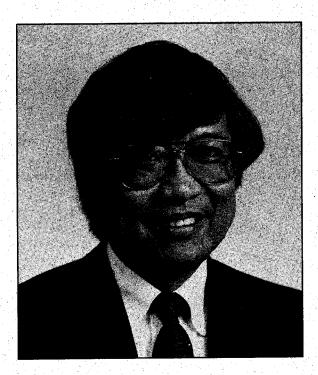
ALICE CHIANG received a B.S. in Physics from the National Taiwan University and a Ph.D. in Physics from Virginia Polytechnic Institute. She is currently a Senior Staff Member in the Microelectronics Group of the Laboratory's Solid State Division.

INVENTION: A CHARGE-DOMAIN PARALLEL PROCESSING NETWORK

A parallel processing architecture was developed based on charge-domain local memories and computing elements. A floating-gate charge-coupled device (CCD) tapped delay line is used for holding and shifting analog charge packets of sampled data. Using an array (or a matrix) of CCD digital-analog multipliers, the output is a charge packet proportional to the sum of the products of the analog sampled data and a set of digital words.

This invention is ideally suited for high-speed, real-time access and computation of a large amount of data in a low-cost, low-power image processing system. Possible applications include aircraft- or spacecraft-mounted weather radar or collision avoidance radar, nationwide computer and time sharing networks for teleconferenced image sharing, medical consultation, multispectral satellite images, facsimile transmission of images ranging from fingerprints to text, and image transmissions over existing telephone networks.

United States patent 4,464,726 has been granted for this invention.



DR. JOHN C.C. FAN'S TRANSPARENT HEAT MIRROR INVENTION PROVIDES HIGH SOLAR TRANSMISSION WITH MINIMAL THERMAL RADIATION LOSS.

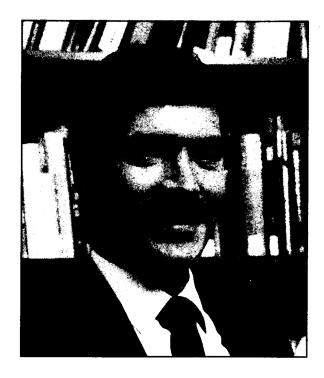
JOHN FAN received a B.S. in Electrical Engineering from the University of California, Berkeley and an M.S. and a Ph.D. in Applied Physics from Harvard University. He is currently the Chairman and Chief Executive Officer of Kopin Corporation in Taunton, Massachusetts. Before founding Kopin in 1984, he was the Associate Group Leader of the Electronic Materials Group in the Laboratory's Solid State Division.

INVENTION: TRANSPARENT HEAT MIRROR

Working with a colleague, John has been granted several patents for the concept of a transparent, composite film, heat mirror. These include a discrete and continuous layer of metallic silver sandwiched between an outer, protective layer that is both transparent and antireflective and a transparent, phase-matching layer. This combination of layers is chosen to provide high solar transmission with minimum loss of thermal radiation.

Transparent heat mirrors allow sunlight and visible light through, but reflect infrared and thermal energy. Some of the applications are coatings for thermal solar collectors, energy saving lightbulbs, thermal windows, and transparent furnaces.

United States patents 4,721,349; 4,556,277; and 4,337,990 have been granted for this concept. These patents have been licensed by MIT to industrial companies, and energy-saving commercial products are available.



DR. MATTHEW W. GANZ DEVELOPED A TECHNIQUE MAKING RADAR SYSTEMS ROBUST IN CONGESTED SIGNAL ENVIRONMENTS.

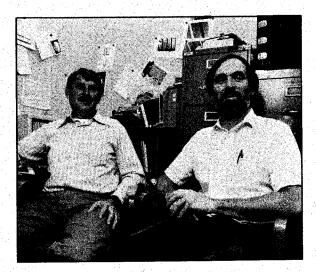
MATTHEW GANZ from Ohio State University, Columbus. He is currently an Assistant Group Leader in the Radar Systems Group of the Laboratory's Radar Measurements Division.

Invention: Adaptive Sidelobe Blanker

Modern radar environments are often so congested with multiple signals that both interference and undesired reflections are experienced. Interference or large target returns in the antenna sidelobe region can either mask main-beam targets or cause false detections. In some applications, such interference may be intentionally generated to distract and impede the effectiveness of a radar system.

A technique was developed that allows two interference rejection techniques — adaptive nulling and sidelobe blanking — to be used simultaneously. Each technique prevents a different type of interference and their simultaneous use makes radar systems more robust in congested signal environments. Multiple adaptive antenna patterns are formed for a phased array radar. The signals from the antenna elements are sampled and a covariance matrix formed. The sample matrix inversion technique is implemented using different steering vectors to calculate adapted weights for both the main beam (or beams) and the sidelobe blanker.

United States patent 4,959,653 has been granted for this invention.



MR. NIKOLAY N. EFREMOW, DR. MICHAEL W. GEIS, AND PROFESSOR HENRY I. SMITH'S (NOT SHOWN), DIAMOND FILM MOSAICS PRODUCE NEAR SINGLE CRYSTAL QUALITY.

MICHAEL GEIS received a B.A. in Physics, an M.S. in Electrical Engineering, and a Ph.D. in Space Physics and Astronomy, all from Rice University. He is currently a Staff Member in the Submicrometer Technology Group of the Laboratory's Solid State Division.

HENRY SMITH received a B.S. in Physics from Holy Cross, and an M.S. and a Ph.D. in Physics from Boston College. While at the Laboratory, Henry was Assistant Leader in the Microelectronics Group. He is currently the Joseph F. and Nancy P. Keithly Professor of Electrical Engineering at the Massachusetts Institute of Technology.

NIKOLAY EFREMOW received an Associate's Degree in Electrical Engineering from Franklin Institute. He is an Assistant Staff Member in the Submicrometer Technology Group of the Laboratory's Solid State Division.

INVENTION: GROWTH OF LARGE AREA MOSAIC DIAMOND FILMS, APPROACHING SINGLE CRYSTAL QUALITY

Diamond's superior properties of heat conductivity, hardness, high breakdown voltage, and transparency to infrared rays make it a material of great potential value for many important commercial and military applications. However, the inability to obtain large area, single crystal diamond films has limited its practical applicability.

A new technique has been developed that produces large area mosaic films approaching single crystal quality. A silicon substrate is patterned and etched to form saw-tooth gratings or tetrahedral etched pits that conform to the shape of commercially available faceted diamond seeds. When single crystal seeds are deposited on this substrate, they become oriented with respect to the etched structures. When these seeds are used as the starting material for epitaxial growth, large areas of continuous mosaic diamond films are produced, which approach the crystallographic properties of single crystal diamond. At this time there is no other way to obtain such a large area diamond film with this degree of crystal quality approaching a single crystal diamond.

A patent application for this invention has been filed.



DR. LEONARD M. JOHNSON DEMONSTRATES AN APPARATUS FOR IMPROVING THE LINEARITY OF INTEGRATED-OPTICAL MODULATORS HAVING MILITARY AND COMMERCIAL USE.

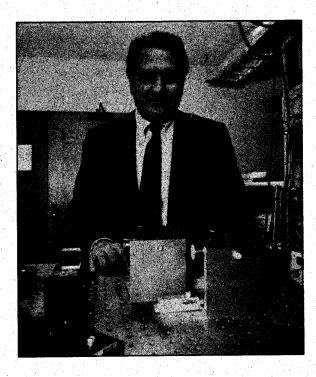
LEONARD JOHNSON a native of Massachusetts, received his S.B., S.M., and Ph.D. degrees, all in Electrical Engineering, from the Massachusetts Institute of Technology. He is currently a Staff Member in the Electrooptical Devices Group of the Laboratory's Solid State Division.

INVENTION: APPARATUS AND METHOD FOR REDUCING MODULATOR NONLINEARITIES

An apparatus and method have been conceived and demonstrated for reducing optical modulator nonlinearities. High-linearity optical modulators are required for accurately transmitting analog signals with low distortion on low-loss optical fibers. The basic technique that has been developed for improving the linearity (optical transmission versus applied voltage) of integratedoptical modulators involves a cancellation scheme based on operating the modulator in two optical polarization states simultaneously. Using this technique, linear optical modulation at frequencies up to tens of gigahertz can be obtained.

Analog fiber-optic links employing linearized integrated-optical modulators are becoming increasingly attractive for both military and commercial applications, including phased-array radar signal distribution and cable television fiber-optic networks.

A patent application for this invention has been filed.



DR. ARAM MOORADIAN INVENTED A SOLID STATE LASER THAT HAS OPTICAL COMMUNICATIONS, LASER PRINTING, AND MEDICAL LASER APPLICATIONS, AMONG OTHERS.

ARAM MOORADIAN received a B.S. in Physics from the Worcester Polytechnic Institute and a Ph.D., also in Physics, from Purdue University. He is currently the Group Leader of the Quantum Electronics Group in the Laboratory's Solid State Division.

INVENTION: SOLID STATE LASER

Aram has invented a solid state, optically pumped microlaser. Although the laser is very small, it operates with precision frequency control, narrow linewidth, and tunability. It can be mass produced at very low cost using semiconductor processing and packaging technology.

Applications include optical communications, laser printing, projection display (including consumer television), robotics control, medical laser uses, and materials processing.

United States patent 4,860,304 has been granted for this invention.



A. GREGORY ROCCO, JR. DESIGNED A DEVICE CAPABLE OF PREVENTING MAJOR COMPUTER NETWORK DISRUPTIONS.

A. GREGORY ROCCO University of New Hampshire and an M.S., also in Electrical Engineering, from Purdue University. He is currently a Staff Member in the Battlefield Surveillance Group of the Laboratory's Surveillance and Control Division.

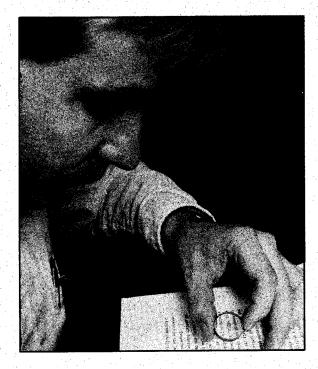
Invention: Autosplit

A token passing ring is a method of interconnecting computer systems. The machines or nodes are connected in series, with the output of one machine feeding the input to the next, creating a network in the form of a unidirectional communications ring. Any node in this ring may originate a message that is then passed from one node to the next until it arrives at its destination node. Normally, if the ring is broken, it goes down and the machines on the ring can no longer communicate with each other.

In installations of more than a few nodes, the ring is divided into subrings. These subrings are connected together at one or more central locations. At these locations there are switches that allow each subring to be switched in and out of the network. When any subring goes down, the entire network can be affected until the faulty subring is identified by an operator and switched off the main network. This restores network communications to all machines in the network except those on the malfunctioning subring. It takes time to recognize that the network is down, locate the malfunctioning subring, and flip the appropriate switch. Since it is not uncommon for system jobs to be run overnight or, in some cases, for several days, a system abort can be quite a serious disruption for many users.

Greg has invented a device he calls "Autosplit," which is designed to automatically recognize a network failure and switch out the faulty subring. This will generally be done fast enough to prevent a major disruption in ongoing work, except, of course, for the nodes on the malfunctioning subring.

A patent application has been filed.



DR. GARY J. SWANSON LOOKS THROUGH A DIFFRACTIVE/REFRACTIVE LENS THAT WILL IMPROVE VISUAL IMAGE AND COLOR IN BIFOCAL LENS IMPLANTS.

GARY SWANSON received a B.S. in Mathematics and a Ph.D. in Physics from the University of Michigan. He is currently a Staff Member in the Laser Radar Measurements Group of the Laboratory's Optics Division.

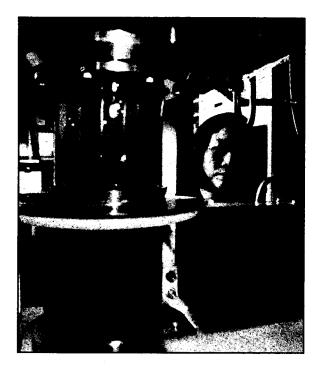
INVENTION: DIFFRACTIVE/REFRACTIVE LENS IMPLANT

Cataract patients commonly have their damaged natural lenses removed and replaced with artificial lens implants. The lenses usually implanted are refractive, i.e., they refract, or bend, light passing through them. The refractive lenses that are usually implanted only correct the focus on distant objects so patients need eyeglasses to see objects closer to them.

Diffraction is the breaking up or scattering of light as it passes by objects in its path. This effect can be achieved on a lens by covering its surface with a series of stepped ridges or notches. By constructing a "binary" lens that has both refractive and diffractive areas, bifocal vision is possible in one implanted lens.

This invention uses a nonrotationally symmetric diffractive structure placed on a refractive lens implant. The advantage of this design over other diffractive/refractive designs is an increase in image clarity and a reduction in false image coloration.

A patent application for this invention has been submitted.



DR. CHRISTINE A. WANG (IN PHOTO), PROFESSOR ROBERT A.BROWN, AND MR. JAMES W. CAUNT BUILT A REACTOR THAT PRODUCES SEMICONDUCTOR FILMS USED IN SPACE COMMUNICATIONS, OPTICAL RECORDING, AND OPTICAL COMPUTING.

CHRISTINE WANG received an S.B. in Materials Science and Engineering, an S.M. in Metallurgy, and a Ph.D. in Electronic Materials, all from the Massachusetts Institute of Technology. She is currently a Staff Member in the Electronic Materials Group of the Laboratory's Solid State Division.

JAMES CAUNT received an Associate's Degree in Mechanical Engineering from the Wentworth Institute of Technology, a B.S. in Industrial Technology from Northeastern University, and an MBA from Babson College. He is currently an Assistant Staff Member in the Laboratory's Solid State Division.

ROBERT BROWN received a B.S. and an M.S. from the University of Texas at Austin and a Ph.D. from the University of Minnesota. He is currently the Arthur D. Little Professor and Head of the Department of Chemical Engineering at the Massachusetts Institute of Technology.

INVENTION: VAPOR PHASE REACTOR FOR MAKING MULTILAYER STRUCTURES

A new reactor for producing semiconductor epitaxial layers such as GaAs, AlGaAs, and InGaAs has been designed, built, and tested. Results show that the reactor produces the most precisely controlled and uniform semiconductor films reported to date. Recognizing that the specific dynamics of the gas in the reactor have a profound influence on film quality, the researchers used a light-scattering technique to visualize the gas flow in the reactor. A numerical model of

reactor fluid flow and heat and mass transfer was developed to simulate epitaxial growth and to establish critical parameters for fabricating uniform layers with abrupt compositional changes.

The reactor, which permits the highly reproducible production of these epilayers, will increase yields and reduce production costs. The uniformity is especially critical for diode-pumped solid state lasers used in military applications, micro- and macro-machining, and medical applications, as well as for coherent diode laser arrays used in space communications, optical recording, and optical computing. In addition, reduced maintenance and simplicity of design are attractive for commercialization.

This invention has received a Notice of Allowability. The Air Force is soliciting proposals for an SBIR (Small Business Innovative Research) grant to develop this concept into a commercial product.

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3,768,417	Transportation System Employing an Electromagnetically Suspended, Guided and Propelled Vehicle	THORNTON, R.D. Kolm, H.H.	30 Oct 73
3,789,327	Micro-Acoustic Waveguide	Waldron, R.A. Stern, E.	29 Jan 74
3,794,844	Method and Means of Construction of a Semiconductor Material for Use in a Laser	Dimmock, J.O. Melngailis, I. Strauss, A.J.	26 Feb 74
3,818,243	Error Correction by Redundant Pulse Powered Circuits	McMahon, R.E.	18 Jun 74
3,831,173*	Ground Radar System	LERNER, R.M.	20 Aug 74
3,842,751	Transportation System Employing an Electromagnetically Suspended, Guided and Propelled Vehicle	THORNTON, R.D. Kolm, H.H.	22 Ост 74
3,857,990	Heat Pipe Furnace	Steininger, J. Reed, T.B.	31 Dec 74
3,863,070	Quantum Mechanical MOSFET Infrared Radiation Detector	WHEELER, R.H. Ralston, R.W.	28 Jan 75
3,869,618	High-Power Tunable Far-Infrared and Submillimeter Source	Lax, B. Aggarwal, R.L.	4 Mar 75
3,871,017	High-Frequency Phonon Generating Apparatus and Method	Pratt, G.W., Jr.	11 Mar 75
3,871,215	Opto-Electronic Apparatus to Gener- ate a Pulse-Modulated Signal Indica- tive of the Mechanical State of a System	Pratt, G.W., Jr. McMullin, P.G.	18 Mar 75

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* PATENT HAS BEEN LICENSED

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3,871,301	STABILIZATION AND RIDE CONTROL OF SUSPENDED VEHICLES PROPELLED BY A LINEAR MOTOR	Kolm, H.H. Thornton, R.D.	18 Mar 75
3,879,235	Method of Growing from Solution Materials Exhibiting a Peltier Effect at the Solid-Melt Interface	Gatos, H.C. Witt, A.F. Lichtensteiger, M.	22 Apr 75
3,883,831	Surface Wave Devices	Williamson, R.C. Stern, E.	13 May 75
3,886,530*	Signal Storage Device	Huber, E.E., Jr. Cohen, M.S., Jr. Smith, D.O.	.27 May 75
3,887,937	Semiconductor Sensor	Gatos, H.C. Lagowski, J.	3 Jun 75
3,897,766	Apparatus Adapted to Opto- Electrically Monitor the Output of a Prime Mover to Provide Sig- nals Which Are Fed Back to the Input and Thereby Provide Control of the Prime Mover	Pratt, G.W., Jr. McMullin, P.G.	5 Sep 75
3,912,394	Method and System of Inter- ferometric Measurements of Modulation Transfer Functions	Kelsall, D.	14 Ост 75
3,927,385	LIGHT EMITTING DIODE	Pratt, G.W., Jr.	16 Dec 75
3,941,670	Method of Altering Biological and Chemical Activity of Mole- cular Species	Pratt, G.W., Jr.	2 Mar 76
3,950,645	Infrared Detection Tube	Rotstein, J. Keyes, R.J.	13 Apr 76
3,963,515	Vacuum Cleaning	Haldeman, C.W. Covert, E.E.	15 Jun 76
3,965,277	Photoformed Plated Interconnection of Embedded Integrated Circuit Chips	Guditz, E.A. Burke, R.L.	22 Jun 76
3,974,382*	Lithographic Mask Attraction System	Bernacki, S.E.	10 Aug 76

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3,974,412	Spark Plug Employing Both Corona Discharge and Arc Discharge and a System Employing the Same	Pratt, G.W., Jr.	10 Aug 76
3,984,680	Soft X-Ray Mask Alignment System	Smith, H.I.	5 Ост 76
4,011,745	Semiconductor Sensors	Gatos, H.C. Lagowski, J.	15 Mar 77
4,016,412	Surface Wave Devices for Processing Signals	Stern, E. Williamson, R.C.	5 Apr 77
4,020,388	Discharge Device	Pratt, G.W., Jr.	26 Apr 77
4,027,383	Integrated Circuit Packaging	Herndon, T.O. Raffel, J.I.	7 Jun 77
4,038,216	Material and Method of Making Secondary-Electron Emitters	Henrich, V.E. Fan, J.C.C.	26 Jul 77
4,049,891	Compositions for Fast Alkali- Metal-Ion Transport	Hong, H.Y-P. Goodenough, J.B.	20 Sep 77
4,055,758	SURFACE WAVE DEVICES FOR PRO- CESSING SIGNALS	Stern, E. Williamson, R.C. Bers, A. Cafarella, J.H.	25 Ост 77
4,059,461*	Method for Improving the Crystal- linity of Semiconductor Films by Laser Beam Scanning and the Products Thereof	Fan, J.C.C. Zeiger, H.J.	22 Nov 77
4,063,105	Method of and Apparatus for Genera- ting Tunable Coherent Radiation by Noncollinear Phase-Matched Sum- Difference Frequency Optical Mixing	Aggarwal, R.L. Lee, N.K. Lax, B.	13 Dec 77
4,066,984	Surface Acoustic Wave Devices for Processing and Storing Signals	Stern, E. Ingebrigtsen, K.A.	3 Jan 78
4,067,037	Transistor Having High FT at Low Currents	Greiff, P.	3 Jan 78
4,075,706	Surface Wave Devices for Pro- cessing Signals	Stern, E. Williamson, R.C. Smith, H.I.	21 Feb 78

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4,087,719	Spark Plug	Pratt, G.W., Jr.	2 May 78
4,087,976	Electric Power Plant Using Electro- lytic Cell-Fuel Cell Combination	Morrow, W.E., Jr. Hsu, M.S.	9 May 78
4,093,927*	Pulsed Gas Laser	Levine, J.S.	6 Jun 78
4,101,965	SURFACE ACOUSTIC WAVE DEVICES FOR PROCESSING AND STORING SIGNALS	Ingebrigtsen, K.A. Bers, A. Cafarella, J.H.	18 Jul 78
4,107,544	Two-Photon Resonant Laser Mixing in Molecular Liquids	Kildal, H. Brueck, S.R.J.	15 Aug 78
4,115,228	Method of Making Secondary Electron Emitters	Henrich, V.E. Fan, J.C.C.	19 Sep 78
4,115,280	Apparatus for Altering the Biological and Chemical Activity of Molecular Species	Pratt, G.W., Jr.	19 Sep 78
4,117,103	LITHIUM ION TRANSPORT COMPOSITIONS	Hong, H.Y-P.	26 Sep 78
4,119,855	Nonvacuum Soft X-Ray Litho- graphic Source	Bernacki, S.E.	10 Ост 78
4,127,900	Reading Capacitor Memories with a Variable Voltage Ramp	Raffel, J.I. Yasaitis, J.A.	28 Nov 78
4,140,369	EFFICIENT LIGHT DIFFUSER	Howland, B.	20 Feb 79
4,142,924*	Fast-Sweep Growth Method for Growing Layers Using Liquid Phase Epitaxy	Hsieh, J.J.	6 Mar 79
4,150,177	Method for Selectively Nickeling a Layer of Polymerized Polyester Resin	Guditz, E.A. Burke, R.L.	17 Apr 79
4,166,669	Planar Optical Waveguide, Modulator, Variable Coupler and Switch	Leonberger, F.J. Donnelly, J.P.	4 Sep 79
4,170,512	Method of Manufacture of a Soft-X-Ray Mask	Flanders, D.C. Smith, H.I. Dalomba, M.A.	9 Ост 79
4,172,882	LITHIUM ION TRANSPORT COMPOSITIONS	Hong, H.Y-P.	30 Ост 79

4,184,172*	Dielectric Isolation Using Shallow Oxide and Polycrystalline Silicon	Raffel, J.I. Bernacki, S.E.	15 Jan 80
4,186,045	Method of Epitaxial Growth Employing Electromigration	Gatos, H.C. Jastrzebski, L.L.	29 Jan 80
4,197,141*	Method for Passivating Imperfections in Semiconductor Materials	Bozler, C.O. Fan, J.C.C.	8 Apr 80
4,200,395	ALIGNMENT OF DIFFRACTION GRATINGS	Smith, H.I. Austin, S.S. Flanders, D.C.	29 Apr 80
4,220,510	Method for Separating Isotopes in the Liquid Phase at Cryogenic Temperature	Brueck, S.R.J. Osgood, R.M., Jr.	2 Sep 80
4,227,941*	Shallow-Homojunction Solar Cells	Bozler, C.O. Chapman, R.L. Fan, J.C.C. McClelland, R.W.	14 Ост 80
4,231,819	Dielectric Isolation Method Using Shallow Oxide and Polycrystalline Silicon Utilizing a Preliminary Etching Step	Raffel, J.I. Bernacki, S.E.	4 Nov 80
4,242,736	Capacitor Memory and Methods for Reading, Writing, and Fabricating Capacitor Memories	Raffel, J.I. Yasaitis, J.A.	30 Dec 80
4,248,675*	Method of Forming Electrical Contact and Antireflection Layer on Solar Cells	Bozler, C.O. Chapman, R.L. Fan, J.C.C. McClelland, R.W.	3 Feb 81
4,248,687*	Method of Forming Transparent Heat Mirrors on Polymeric Substrates	Fan, J.C.C.	3 Feb 81
4,254,174	Supported Membrane Composite Structure and Its Method of Manufacture	Flanders, D.C. Smith, H.I. Dalomba, M.A.	3 Mar 81
4,256,787	Orientation of Ordered Liquids and Their Use in Devices	Shaver, D.C. Smith, H.I. Flanders, D.C.	17 Mar 81

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4,257,690	Eye Testing Chart	Howland, B.	24 Mar 81
4,258,375*	GaInAsP/InP Avalanche Photodiode and Method for Its Fabrication	Hsieh, J.J. Hurwitz, C.E.	24 Mar 81
4,268,095	Magnetic Bearing	MILLNER, A.R.	19 May 81
4,268,808	Acoustic Wave Device	Melngailis, J.	19 May 81
4,274,737	TEST PATTERNS FOR LENS EVALUATION	Howland, B.	23 Jun 81
4,283,235	Dielectric Isolation Using Shallow Oxide and Polycrystalline Silicon Utilizing Selective Oxidation	Raffel, J.I. Bernacki, S.E.	11 Aug 81
4,287,235	X-Ray Lithography at (About) 100 Angstroms Linewidths Using X-Ray Masks Fabricated by Shadowing Techniques	Flanders, D.C.	1 Sep 81
4,287,485*	GaInAsP/InP Double- Heterostructure Lasers	Hsieh, J.J.	1 Sep 81
4,290,118	Solid State Devices Combining the Use of Surface-Acoustic- Wave Devices and Charge- Coupled Devices	Stern, E. Ralston, R.W. Smythe, D.L., Jr. Burke, B.E.	15 Sep 81
4,291,390	Analog Solid State Memory	Stern, E. Ralston, R.W. Smythe, D.L., Jr. Burke, B.E.	22 Sep 81
4,298,280	Infrared Radar System	Harney, R.C.	3 Nov 81
4,298,953	Programmable Zero-Bias Floating Gate Tapping Method and Apparatus	Munroe, S.C.	3 Nov 81
4,309,225*	Method of Crystallizing Amorphous Material with a Moving Energy Beam	Fan, J.C.C. Zeiger, H.J.	5 Jan 82
4,312,915	CERMET FILM SELECTIVE BLACK ABSORBER	Fan, J.C.C.	26 Jan 82
4,313,159	DATA STORAGE AND ACCESS APPARTUS	Shoap, S.D.	26 Jan 82
4,313,178	Analog Solid State Memory	Stern, E. Ralston, R.W.	26 Jan 82

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JUNCTIONS AND PROCESS FOR PRODUCING SAMECHI, J-Y.4,323,422METHOD FOR PREPARING OPTICALLY FLAT DAMAGE-FREE SURFACECALAWA, A.R. GORMLEY, J.V. MANFRA, M.J.6 Apr 82 GORMLEY, J.V. MANFRA, M.J.4,333,792ENHANCING EPITAXY AND PREFERRED ORIENTATIONSMITH, H.I.8 JUN 82 ORIENTATION4,337,990*TRANSPARENT HEAT-MIRRORFAN, J.C.C. BACHNER, F.J.6 JUL 82 BACHNER, F.J.4,340,305PLATE ALIGNINGSMITH, H.I. AUSTIN, S.S. FLANDERS, D.C.20 JUL 8. AUSTIN, S.S. FLANDERS, D.C.4,340,617*METHOD AND APPARATUS FOR DEPOSITING A MATERIAL ON A SURFACEDEUTSCH, T.F. OSGOOD, R.M., JR.20 JUL 8. AUSTIN, J.4,342,970ACOUSTIC WAVE DEVICEMELINGAILS, J. HAUS, H.A. LATTES, A.L.3 AUG 8. HAUS, H.A. LATTES, A.L.3 AUG 8. HAUS, H.A. LATTES, A.L.4,350,586SPATIAL PERIOD DIVISION EXPOSINGFLANDERS, D.C. SMITH, H.I.23 Nov 3 SMITH, H.I.4,366,338*COMPENSATING SEMICONDUCTOR MATERIALSFAN, J.C.C. SALERNO, J.P.23 Nov 3 SMITH, H.I.4,366,338*COMPENSATING SEMICONDUCTOR MATERIALSTURNER, G.W. FAN, J.C.C. SALERNO, J.P.24 DEC & FAN, J.C.C. SALERNO, J.P.4,370,194ORIENTATION OF ORDERED LIQUIDS AND THEIR USE IN DEVICESSHAVER, D.C. SMITH, H.I. FLANDERS, D.C. SMITH, H.I. FLANDERS, D.C. SALERNO, J.P.				
FLAT DAMAGE-FREE SURFACEGORMLEY, J.V. MANFRA, M.J.4,333,792ENHANCING EPITAXY AND PREFERREDSMITH, H.I.8 JUN 82(4,337,990*)TRANSPARENT HEAT-MIRRORFAN, J.C.C. BACHNER, F.J.6 JUL 824,340,305PLATE ALIGNINGSMITH, H.I. AUSTIN, S.S. FLANDERS, D.C.20 JUL 84,340,617*METHOD AND APPARATUS FOR DEPOSITING A MATERIAL ON A SURFACEDEUTSCH, T.F. OSGOOD, R.M., JR.20 JUL 84,342,970ACOUSTIC WAVE DEVICEMELINGAILIS, J. HAUS, H.A. LATTES, A.L.3 AUG 824,352,105DISPLAY SYSTEMHARNEY, R.C.28 SEP 84,350,586SPATIAL PERIOD DIVISION EXPOSING MATERIALSFLANDERS, D.C. SMITH, H.I.23 Nov 44,366,338*COMPENSATING SEMICONDUCTOR MATERIALSTURNER, G.W. FAN, J.C.C. SALENO, J.P.28 DEC 84,370,194ORIENTATION OF ORDERED LIQUIDS AND THEIR USE IN DEVICESSMITH, H.I. FAN, J.C.C. SALENO, J.P.25 JAN 84,371,421LATERAL EPITAXIAL GROWTH BY SEEDED SOLIDIFICATIONFAN, J.C.C. GEIS, M.W.1 FEB 83	4,320,247	JUNCTIONS AND PROCESS FOR PRODUCING		16 Mar 82
ORIENTATION4,337,990*TRANSPARENT HEAT-MIRRORFAN, J.C.C. BACHNER, F.J.6 JUL 82 BACHNER, F.J.4,340,305PLATE ALIGNINGSMITH, H.I. AUSTIN, S.S. FLANDERS, D.C.20 JUL 83 AUSTIN, S.S. FLANDERS, D.C.4,340,617*METHOD AND APPARATUS FOR DEPOSITING A MATERIAL ON A SURFACEDEUTSCH, T.F. OSGOOD, R.M., JR.20 JUL 83 AUSTIN, J.4,342,970ACOUSTIC WAVE DEVICEMELINGAILIS, J. HAUS, H.A. LATTES, A.L.3 AUG 83 HAUS, H.A. LATTES, A.L.3 AUG 83 HAUS, H.A. LATTES, A.L.4,352,105DISPLAY SYSTEMHARNEY, R.C. SULCON ON SULCON UTILIZING ALLOYING CONTROL2 Nov 83 SULCON ON SULCON UTILIZING ALLOYING CONTROL4,360,586SPATIAL PERIOD DIVISION EXPOSINGFLANDERS, D.C. SMITH, H.I.23 Nov 43 SMITH, H.I.4,366,338*COMPENSATING SEMICONDUCTOR MATERIALSTURNER, G.W. SALERNO, J.P.28 DEC 8 SMITH, H.I. FLANDERS, D.C.4,370,194ORIENTATION OF ORDERED LIQUIDS AND THEIR USE IN DEVICESSHAVER, D.C. SMITH, H.I. FLANDERS, D.C.25 JAN 8 SMITH, H.I. FLANDERS, D.C.4,371,421LATERAL EPITAXIAL GROWTH BY SEEDED SOLUDIFICATIONFAN, J.C.C. GEIS, M.W.1 FEB 83 GEIS, M.W.	4,323,422		Gormley, J.V.	6 Apr 82
BACHNER, F.J.4,340,305PLATE ALIGNINGSMITH, H.I. AUSTIN, S.S. FLANDERS, D.C.20 JUL 8. AUSTIN, S.S. FLANDERS, D.C.4,340,617*METHOD AND APPARATUS FOR DEPOSITING A MATERIAL ON A SURFACEDEUTSCH, T.F. ONGOOD, R.M., JR.20 JUL 8. 20 JUL 8. EHRLICH, D.J. ONGOOD, R.M., JR.4,342,970ACOUSTIC WAVE DEVICEMELNGAILIS, J. HAUS, H.A. LATTES, A.L.3 AUG 8. HAUS, H.A. LATTES, A.L.4,352,105DISPLAY SYSTEMHARNEY, R.C. SILICON ON SILICON UTILIZING ALLOYING CONTROLFAN, J.C.C. SMITH, H.I.20 JUL 8. 20 JUL 8. 21 Nov 8. SILICON ON SILICON UTILIZING ALLOYING CONTROL4,360,586SPATIAL PERIOD DIVISION EXPOSINGFLANDERS, D.C. SMITH, H.I.23 Nov 4. SMITH, H.I.4,366,338*COMPENSATING SEMICONDUCTOR MATERIALSTURNER, G.W. SALERNO, J.P.28 DEC 8. SMITH, H.I.4,370,194ORIENTATION OF ORDERED LIQUIDS AND THEIR USE IN DEVICESSHAVER, D.C. SMITH, H.I. FLANDERS, D.C.25 JAN 8. SMITH, H.I. FLANDERS, D.C.4,371,421LATERAL EPITAXIAL GROWTH BY SEEDED SOLIDIFICATIONFAN, J.C.C. GEIS, M.W.1 FEB 83	4,333,792		Smith, H.I.	8 Jun 82
Austin, S.S. Flanders, D.C.4,340,617*Method and Apparatus for Depositing a Material on a SurfaceDeutsch, T.F. Ehrlich, D.J. Osgood, R.M., Jr.20 Jul 834,342,970Acoustic Wave DeviceMelngallis, J. Haus, H.A. Lattes, A.L.3 Aug 834,352,105Display SystemHarney, R.C.28 Sep 84,357,183*Heteroepitaxy of Germanium Silicon on Silicon Utilizing Alloying ControlFan, J.C.C. Smith, H.I.23 Nov 84,360,586Spatial Period Division Exposing MaterialsFlanders, D.C. Smith, H.I.28 Dec 84,370,194Orientation of Ordered Liquids And Their Use in DevicesShaver, D.C. Smith, H.I. Flanders, D.C.25 Jan 84,371,421Lateral Epitaxial Growth By Seeded SolidificationFan, J.C.C. Geis, M.W.1 Feb 83	4,337,990*	TRANSPARENT HEAT-MIRROR		6 Jul 82
DEPOSITING A MATERIAL ON A SURFACEEHRLICH, D.J. OSGOOD, R.M., JR.4,342,970ACOUSTIC WAVE DEVICEMELNGAILIS, J. HAUS, H.A. LATTES, A.L.3 AUG 80 HAUS, H.A. LATTES, A.L.4,352,105DISPLAY SYSTEMHARNEY, R.C.28 SEP 84,357,183*HETEROEPITAXY OF GERMANIUM SILICON ON SILICON UTILIZING ALLOVING CONTROLFAN, J.C.C. SMITH, H.I.2 Nov 80 SMITH, H.I.4,360,586SPATIAL PERIOD DIVISION EXPOSINGFLANDERS, D.C. SMITH, H.I.23 Nov 80 SMITH, H.I.4,366,338*COMPENSATING SEMICONDUCTOR MATERIALSTURNER, G.W. FAN, J.C.C. SALERNO, J.P.28 Dec 80 SMITH, H.I. FLANDERS, D.C.4,370,194ORIENTATION OF ORDERED LIQUIDS AND THEIR USE IN DEVICESSHAVER, D.C. SMITH, H.I. FLANDERS, D.C.25 JAN 80 SMITH, H.I. FLANDERS, D.C.4,371,421LATERAL EPITAXIAL GROWTH BY SEEDED SOLIDIFICATIONFAN, J.C.C. GEIS, M.W.1 FEB 83 GEIS, M.W.	4,340,305	Plate Aligning	Austin, S.S.	20 Jul 82
Haus, H.A. Lattes, A.L.4,352,105Display SystemHarney, R.C.28 Sep 84,357,183*Heteroepitaxy of Germanium Silicon on Silicon Utilizing Alloying ControlFan, J.C.C. Gale, R.P. Alloying Control2 Nov 84,360,586Spatial Period Division ExposingFlanders, D.C. Smith, H.I.23 Nov 84,366,338*Compensating Semiconductor MaterialsTurner, G.W. Fan, J.C.C. Salerno, J.P.28 Dec 84,370,194Orientation of Ordered Liquids And Their Use in DevicesShaver, D.C. Smith, H.I. Flanders, D.C.25 Jan 84,371,421Lateral Epitaxial Growth By Seeded SolidificationFan, J.C.C. Geis, M.W.1 Feb 83	4,340,617*	Depositing a Material on a	Ehrlich, D.J.	20 Jul 82
4,357,183*Heteroepitaxy of Germanium Silicon on Silicon Utilizing Alloying ControlFan, J.C.C. Gale, R.P.2 Nov 8 Sale, R.P.4,360,586Spatial Period Division ExposingFlanders, D.C. Smith, H.I.23 Nov 8 Smith, H.I.4,366,338*Compensating Semiconductor MaterialsTurner, G.W. Fan, J.C.C. Salerno, J.P.28 Dec 8 Seitend Division Schered Liquids Shaver, D.C.4,370,194Orientation of Ordered Liquids And Their Use in DevicesShaver, D.C. Smith, H.I. Flanders, D.C.25 Jan 8 Seitend Solidification4,371,421Lateral Epitaxial Growth By Seeded SolidificationFan, J.C.C. Geis, M.W.1 Feb 83 Seitend Solidification	4,342,970	Acoustic Wave Device	HAUS, H.A.	3 Aug 82
SILICON ON SILICON UTILIZING ALLOYING CONTROLGALE, R.P.4,360,586SPATIAL PERIOD DIVISION EXPOSINGFLANDERS, D.C. SMITH, H.I.23 Nov 8 SMITH, H.I.4,366,338*COMPENSATING SEMICONDUCTOR MATERIALSTURNER, G.W. FAN, J.C.C. SALERNO, J.P.28 Dec 8 SALERNO, J.P.4,370,194ORIENTATION OF ORDERED LIQUIDS AND THEIR USE IN DEVICESSHAVER, D.C. SMITH, H.I. FLANDERS, D.C.25 JAN 8 SMITH, H.I. FLANDERS, D.C.4,371,421LATERAL EPITAXIAL GROWTH BY SEEDED SOLIDIFICATIONFAN, J.C.C. GEIS, M.W.1 FEB 83 GEIS, M.W.	4,352,105	Display System	Harney, R.C.	28 Sep 82
SMITH, H.I.4,366,338*Compensating Semiconductor MaterialsTurner, G.W. Fan, J.C.C. Salerno, J.P.28 Dec 8 Fan, J.C.C. Salerno, J.P.4,370,194Orientation of Ordered Liquids AND THEIR USE IN DevicesShaver, D.C. Smith, H.I. Flanders, D.C.25 Jan 8 Smith, H.I. Flanders, D.C.4,371,421Lateral Epitaxial Growth By Seeded SolidificationFan, J.C.C. Geis, M.W.1 Feb 83 Geis, M.W.	4,357,183*	Silicon on Silicon Utilizing		2 Nov 82
MATERIALSFAN, J.C.C. SALERNO, J.P.4,370,194ORIENTATION OF ORDERED LIQUIDS AND THEIR USE IN DEVICESSHAVER, D.C. SMITH, H.I. FLANDERS, D.C.25 JAN 8 SEEDED SOLIDIFICATION4,371,421LATERAL EPITAXIAL GROWTH BY SEEDED SOLIDIFICATIONFAN, J.C.C. GEIS, M.W.1 FEB 83 GEIS, M.W.	4,360,586	Spatial Period Division Exposing		23 Nov 82
AND THEIR USE IN DEVICES SMITH, H.I. FLANDERS, D.C. 4,371,421 LATERAL EPITAXIAL GROWTH BY FAN, J.C.C. 1 FEB 83 SEEDED SOLIDIFICATION GEIS, M.W.	4,366,338*		Fan, J.C.C.	28 Dec 82
SEEDED SOLIDIFICATION GEIS, M.W.	4,370,194		Sмітн, H.I.	25 Jan 83
	4,371,421		Geis, M.W.	1 Feb 83

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4,372,791*	Method for Fabricating DH Lasers	Hsieh, J.J.	8 Feb 83
4,372,996	Method for Metallizing Aluminum Pads of an Integrated Circuit Chip	GUDITZ, E.A. Burke, R.L.	8 Feb 83
4,376,228*	Solar Cells Having Ultrathin Active Layers	Fan, J.C.C. Bozler, C.O.	8 Mar 83
4,376,285	High Speed Optoelectronic Switch	Leonberger, F.J. O'Donnell, F.J.	8 Mar 83
4,378,629*	Semiconductor Embedded Layer Technology Including Permeable Base Transistor, Fabrication Method	Bozler, C.O. Alley, G.D. Lindley, W.T. Murphy, R.A.	5 Apr 83
4,382,660	Optical Transistors and Logic Circuits Embodying the Same	Pratt, G.W., Jr. Jain, K.	10 May 83
4,384,299	Capacitor Memory and Methods for Reading, Writing, and Fabricating Capacitor Memories	Raffel, J.I. Yasaittis, J.A.	17 May 83
4,410,237	Method and Apparatus for Shaping Electromagnetic Beams	Veldkamp, W.B.	18 Oct 83
4,420,873	Optical Guided Wave Devices Employing Semiconductor- Insulator Structures	Leonberger, F.J. Melngailis, I. Bozler, C.O. McClelland, R.W.	20 Dec 83
4,426,712	Correlation System for Global Position Receiver	Gorski-Popiel, G.	17 Jan 84
4,438,520	System for Regenerating a Data Word on a Communications Ring	Saltzer, J.H.	20 Mar 84
4,442,166	CERMET FILM SELECTIVE-BLACK ABSORBER	Fan, J.C.C.	10 Apr 84
4,444,992	Photovoltaic-Thermal Collectors	Cox, C.H., III	24 Apr 84
4,447,149	Pulsed Laser Radar Apparatus	Marcus, S. Quist, T.M.	8 May 84
4,454,371	Solar Energy Concentrator System	Folino, F.A.	12 Jun 84
4,458,324	Charge Domain Multiplying Device	BURKE, B.E. Chiang, A.M. Lindley, W.T.	3 Jul 84

4,464,726	Charge Domain Parallel Processing Network	CHIANG, A.M.	7 Aug 84
4,468,850*	GaInAsP/InP Double- Heterostructure Lasers	Liau, Z-L. Walpole, J.N.	4 Sep 84
4,473,805	Phase Lock Loss Detector	Guhn, D.K.	25 Sep 84
4,479,224	Fiber-Coupled External Cavity Semiconductor Laser	REDIKER, R.H.	23 Ост 84
4,479,846	Method of Entraining Dislocations and Other Crystalline Defects in Heated Film Contacting Patterned Region	Smith, H.I. Geis, M.W.	30 Ост 84
4,489,390	Spatial Filter System	Parenti, R.R. Keicher, W.E.	18 Dec 84
4,490,445	Solid Oxide Electrochemical Energy Converter	Hsu, M.S.	25 Dec 84
4,499,441	Superconducting Signal Processing Circuits	Lynch, J.T. Anderson, A.C. Withers, R.S. Wright, P.V.	12 Feb 85
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4,525,871	High Speed Optoelectronic Mixer	Foyt, A.G. Leonberger, F.J. Williamson, R.C.	25 Jun 85

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н, 11 11	4,553,265	Monolithic Single and Double Sideband Mixer Apparatus	Clifton, B.J. Alley, G.D.	12 Nov 85
	4,556,277*	Transparent Heat-Mirror	Fan, J.C.C. Bachner, F.J.	3 Dec 85
	4,558,290	A Compact Broadband Rec- tangular to Coaxial Waveguide Junction	LEE, J.C.	10 Dec 85
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	4,608,117	Maskless Growth of Patterned Films	Ehrlich, D.J. Deutsch, T.F. Osgood, R.M., Jr. Schlossberg, H.	26 Aug 86
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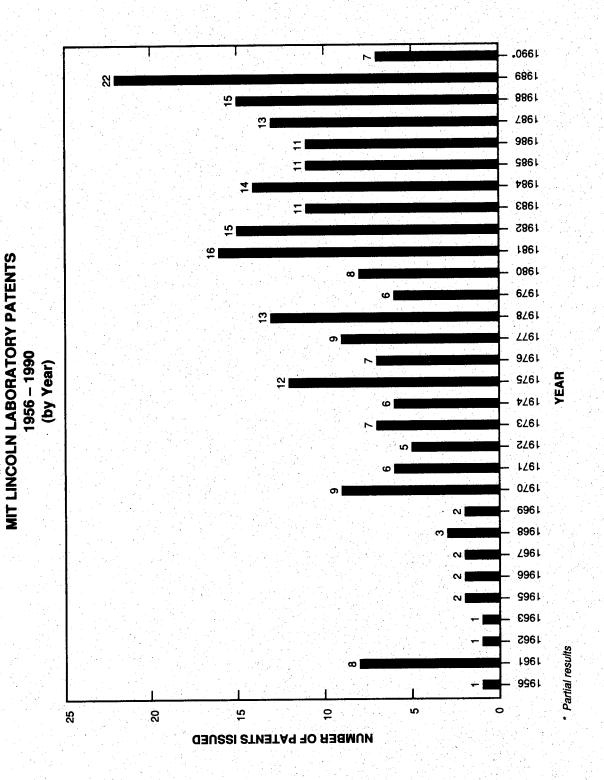
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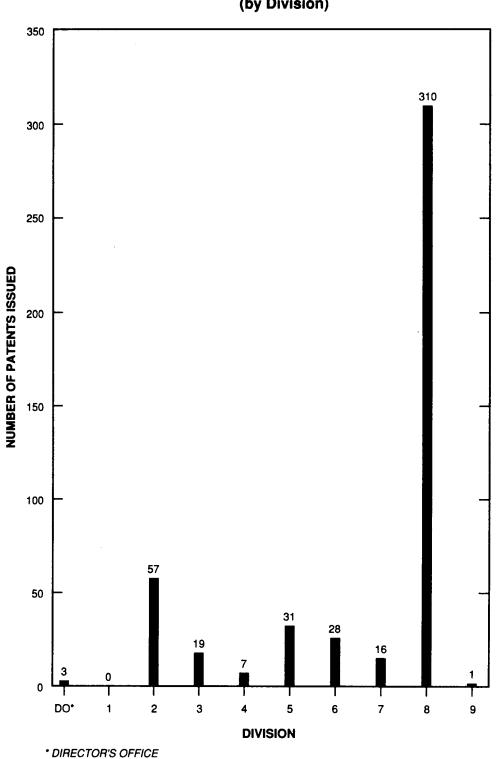
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